

HERMETIC POWER SCHOTTKY RECTIFIER

Very Low Forward Voltage Drop

DESCRIPTION: A 45-VOLT, 120 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC CERAMIC SHD-3/3B HIGH PROFILE PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_C = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

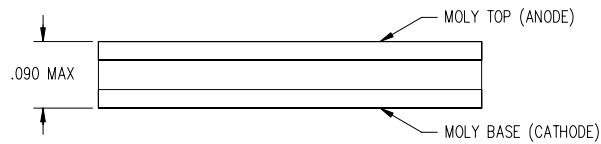
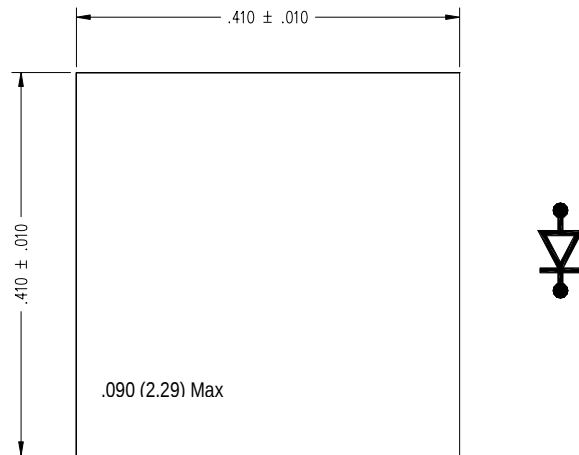
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	45	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C=100^\circ\text{C}$)	I_O	120	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ($t = 8.3\text{ms}$, Sine)	I_{FSM}	1650	Amps
MAXIMUM JUNCTION CAPACITANCE ($V_r=5\text{V}$)	C_T	4800	pF
MAXIMUM THERMAL RESISTANCE	$R_{\theta JC}$	0.20	$^\circ\text{C/W}$
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 175	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

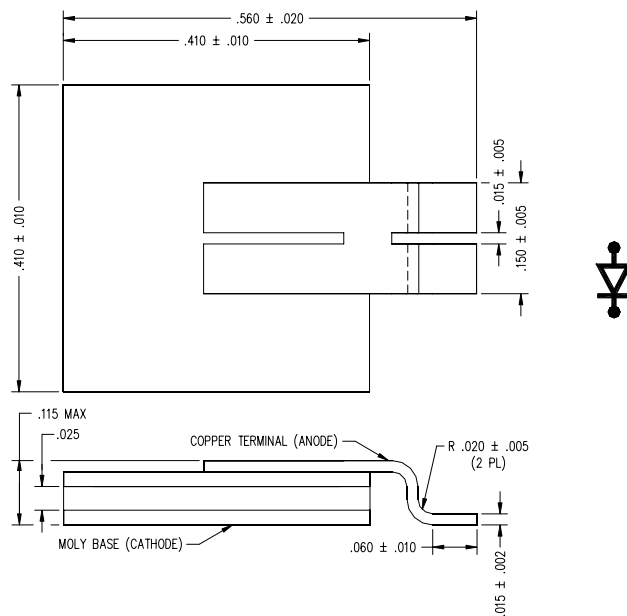
CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 120\text{ Amps}$) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	V_f	0.66 0.59	Volts
MAXIMUM REVERSE CURRENT (I_r @ 45V PIV) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	I_r	2.4 90	mA

TECHNICAL DATA
DATA SHEET 5085, REV. -

MECHANICAL DIMENSIONS: In Inches / mm



SHD-3 HIGH PROFILE



SHD-3B HIGH PROFILE

TECHNICAL DATA
DATA SHEET 5085, REV. -

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